

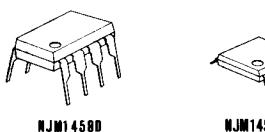
NJM1458

The NJM1458 is a monolithic pair of Internally Compensated High Performance Amplifiers, constructed using the New JRC Planar epitaxial process. They are intended for a wide range of analog applications where board space or weight are important. High common mode voltage range and absence of "latch-up" make the NJM1458 ideal for use as voltage followers. The high gain and wide range of operating voltage provides superior performance in integrator, summing amplifier and general feedback applications.

The NJM1458 is short-circuit protected and require no external components for frequency compensation. The internal 6 dB/octave roll-off insures stability in closed loop applications. For single amplifier performance, see the NJM741 data sheet.

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■ Package Outline



NJM1458D NJM1458M

■ Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

Supply Voltage	V^+/V^-	$\pm 18\text{V}$
Input Voltage (note)	V_I	$\pm 15\text{V}$
Differential Input Voltage	V_{ID}	$\pm 30\text{V}$
Power Dissipation	P_D (D-Type) (M-Type)	500mW 300mW
Operating Temperature Range	T_{opr}	$-20 \sim +75^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-40 \sim +125^\circ\text{C}$

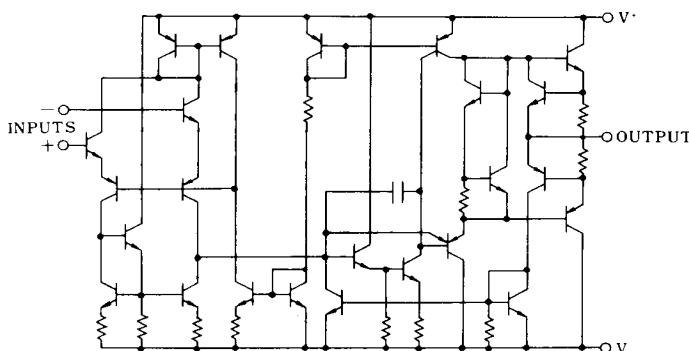
(note) For supply voltages less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

■ Electrical Characteristics ($T_a=25^\circ\text{C}$, $V^+/V^- = \pm 15\text{V}$)

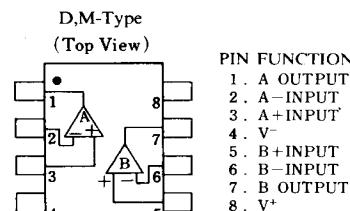
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Input Offset Voltage	V_{IO}	$R_S \leq 10\text{k}\Omega$	—	2.0	6.0	mV
Input Offset Current	I_{IO}		—	30	200	nA
Input Bias Current	I_B		—	60	500	nA
Input Resistance	R_{IN}		0.3	1.0	—	MΩ
Large-signal Voltage Gain	A_V	$R_L \geq 2\text{k}\Omega$, $V_o = \pm 10\text{V}$	86	106	—	dB
Maximum Output Voltage Swing I	V_{OM1}	$R_L \geq 10\text{k}\Omega$	± 12	± 14	—	V
Maximum Output Voltage Swing II	V_{OM2}	$R_L \geq 2\text{k}\Omega$	± 10	± 13	—	V
Input Common Mode Voltage Range	V_{ICM}		± 12	± 13	—	V
Common Mode Rejection Ratio	CMR	$R_S \leq 10\text{k}\Omega$	70	90	—	dB
Supply Voltage Rejection Ratio	SVR	$R_S \leq 10\text{k}\Omega$	76.5	90	—	dB
Supply Current	I_{CC}		—	3.3	5.7	mA
Slew Rate	SR	$R_L \geq 2\text{k}\Omega$, $A_V = 1$	—	0.5	—	V/ μ s
Channel Separation Ratio	CS	f=1kHz	—	98	—	dB

■ Equivalent Circuit

(1/2 Shown)



■ Connection Diagram



D,M-Type
(Top View)

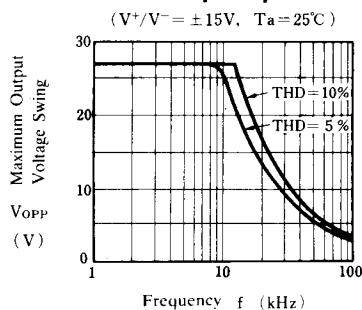
PIN FUNCTION

1. A OUTPUT
2. A-INPUT
3. A+INPUT
4. B+INPUT
5. B-INPUT
6. B OUTPUT
7. GND
8. V+

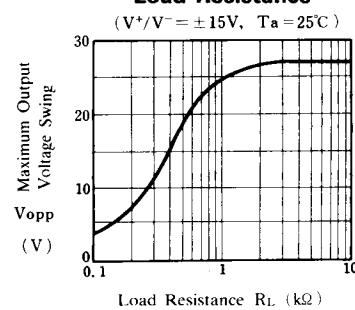
■ Typical Characteristics

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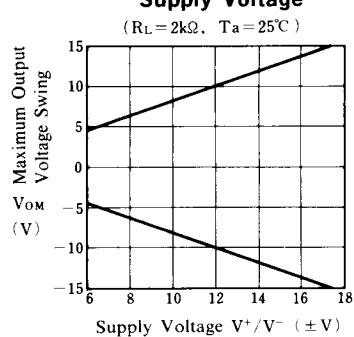
**Maximum Output Voltage Swing
vs.
Frequency**



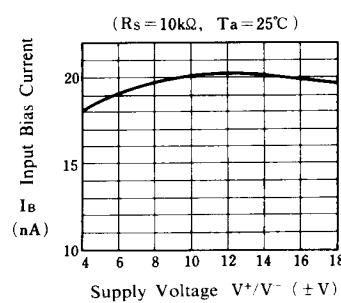
**Maximum Output Voltage Swing
vs.
Load Resistance**



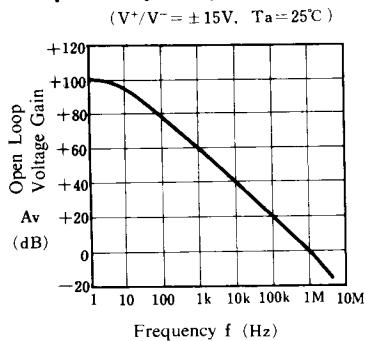
**Maximum Output Voltage Swing
vs.
Supply Voltage**



**Input Bias Current
vs.
Supply Voltage**



Open Loop Frequency Response



**Input Bias Current
vs.
Ambient Temperature**

